

#### 20V NPN LOW SATURATION SWITCHING TRANSISTOR

#### **Features**

- $BV_{CEO} > 20V$
- I<sub>C</sub> = 4.5A Continuous Collector Current
- I<sub>CM</sub> = 15A Peak Pulse Current
- $R_{CE(SAT)} = 38m\Omega$  for a Low Equivalent On-Resistance
- Low Saturation Voltage (75mV max @ 1A)
- h<sub>FE</sub> Characterized up to 15A
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.015 grams (Approximate)

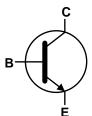
#### **Applications**

- DC-DC Converters
- **Power Management Functions**
- **Power Switches**
- Motor Control

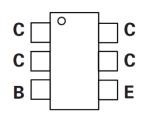
SOT26







Device Symbol



Top View Pin-Out

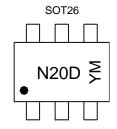
#### Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT13N20DE6TA	AEC-Q101	N20D	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and 1000ppm antimony compounds.
   For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



N20D = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: C = 2015) M or  $\overline{M}$  = Month (ex: 9 = September)

Date Code Key

Year	2015	20	016	2017	2018	2019	2020	202	1 20	22 2	2023	2024	2025
Code	С		D	E	F	G	Н	I		J	K	L	М
Month	1	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code		1	2	3	4	5	6	7	8	9	0	N	D



#### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	20	V
Emitter-Base Voltage	V <sub>EBO</sub>	7.5	V
Base Current	I <sub>B</sub>	500	mA
Continuous Collector Current	Ic	4.5	А
Peak Pulse Collector Current	I <sub>CM</sub>	15	А

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)		1.1 8.8	W	
Linear Derating Factor	(Note 6)	P <sub>D</sub>	1.7 13.6	mW/°C	
Thermal Decistores, Junetics to Ambient	(Note 5)	(Note 5)			
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	73	°C/W	
Thermal Resistance, Junction to Lead (Note 7)		R <sub>0JL</sub>	18.6		
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C		

### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

<sup>5.</sup> For a device mounted with the collector lead on 25mm x 25mm 1oz copper that is on single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

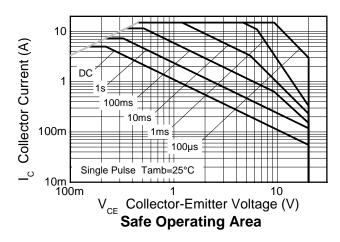
<sup>6.</sup> Same as Note 6, except the device is measured at  $t \le 5$  sec.

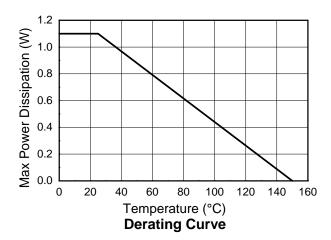
<sup>7.</sup> Thermal resistance from junction to solder-point (at the end of the collector lead).

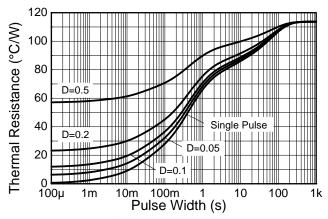
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



### **Thermal Characteristics and Derating Information**







**Transient Thermal Impedance** 



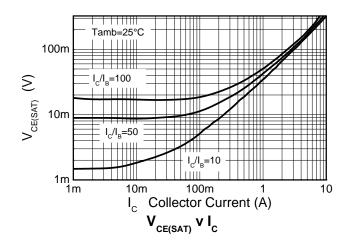
### **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

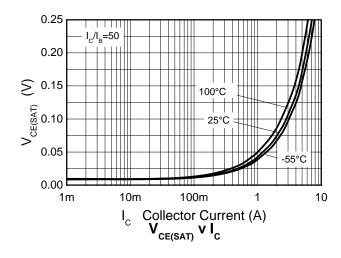
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage		50	100	_	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	20	33	_	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7.5	8.5	_	V	I <sub>E</sub> = 100μA
Collector-Base Cutoff Current	I <sub>CBO</sub>			100	nA	V <sub>CB</sub> = 40V
Emitter Cutoff Current	I <sub>EBO</sub>			100	nA	V <sub>EB</sub> = 6V
Collector-Emitter Cutoff Current	I <sub>CES</sub>	_	1	100	nA	V <sub>CES</sub> = 40V
ON CHARACTERISTICS (Note 9)						
		250	400	_		$I_C = 10$ mA, $V_{CE} = 2$ V
DC Current Gain	h <sub>FE</sub>	300	450	900	_	$I_C = 1A$ , $V_{CE} = 2V$
DC Current Gain		200	300	_		$I_C = 5A$ , $V_{CE} = 2V$
		15	45	1		$I_C = 15A, V_{CE} = 2V$
		_	5	8		$I_C = 100 \text{mA}, I_B = 10 \text{mA}$
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	_	55	75	mV	$I_C = 1A, I_B = 10mA$
			170	230		$I_C = 4.5A$ , $I_B = 45mA$
Base-Emitter Turn-On Voltage	V <sub>BE(on)</sub>		0.85	0.90	V	I <sub>C</sub> = 4.5A, V <sub>CE</sub> = 2V
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f⊤		96	_	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA, f = 50MHz
Output Capacitance	C <sub>obo</sub>	_	50	_	pF	V <sub>CB</sub> = 10V, f = 1MHz
Turn-On Time	t <sub>(on)</sub>	_	115	_	ns	V <sub>CC</sub> = 10V, I <sub>C</sub> = 2A
Turn-Off Time	t <sub>(off)</sub>	_	485	_	ns	$I_{B1} = I_{B2} = 40 \text{mA}$

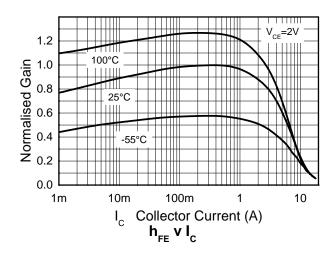
Note: 9. Measured under pulsed conditions. Pulse width  $\leq 300\mu s$ . Duty cycle  $\leq 2\%$ .

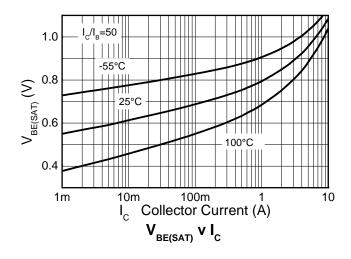


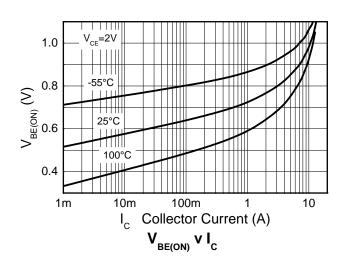
### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







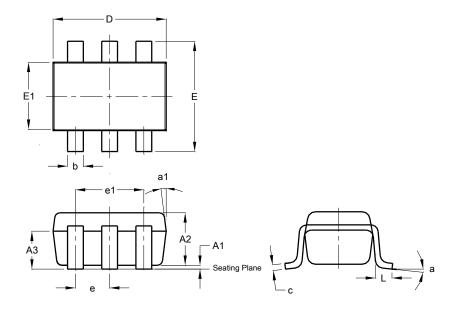






### **Package Outline Dimensions**

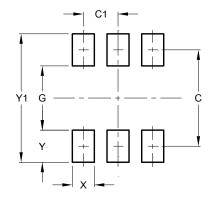
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT26						
Dim	Min	Max	Тур				
A1	0.013	0.10	0.05				
A2	1.00	1.30	1.10				
А3	0.70	0.80	0.75				
b	0.35	0.50	0.38				
С	0.10	0.20	0.15				
D	2.90	3.10	3.00				
е	-	-	0.95				
e1	-	-	1.90				
Е	2.70	3.00	2.80				
E1	1.50	1.70	1.60				
L	0.35	0.55	0.40				
а	-	-	8°				
a1	-	-	7°				
All Dimensions in mm							

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



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